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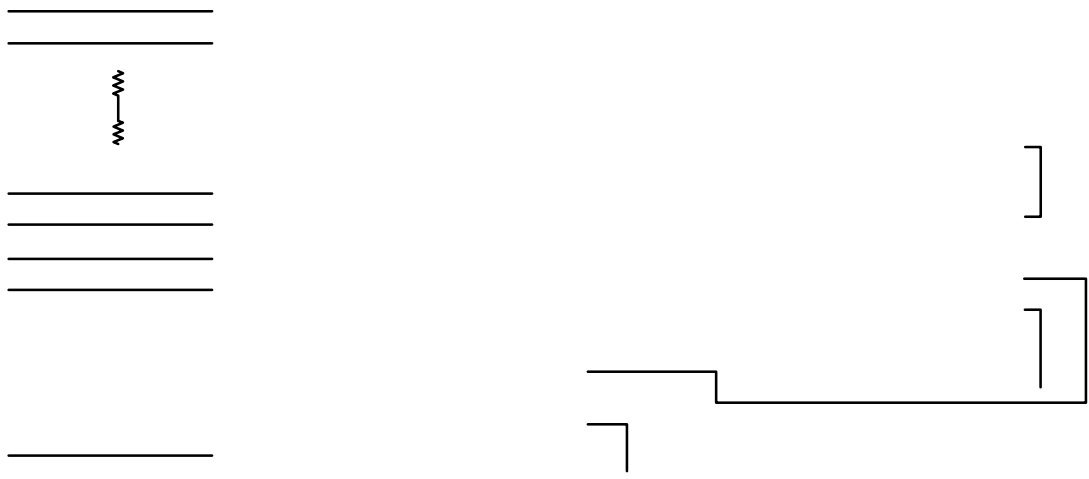
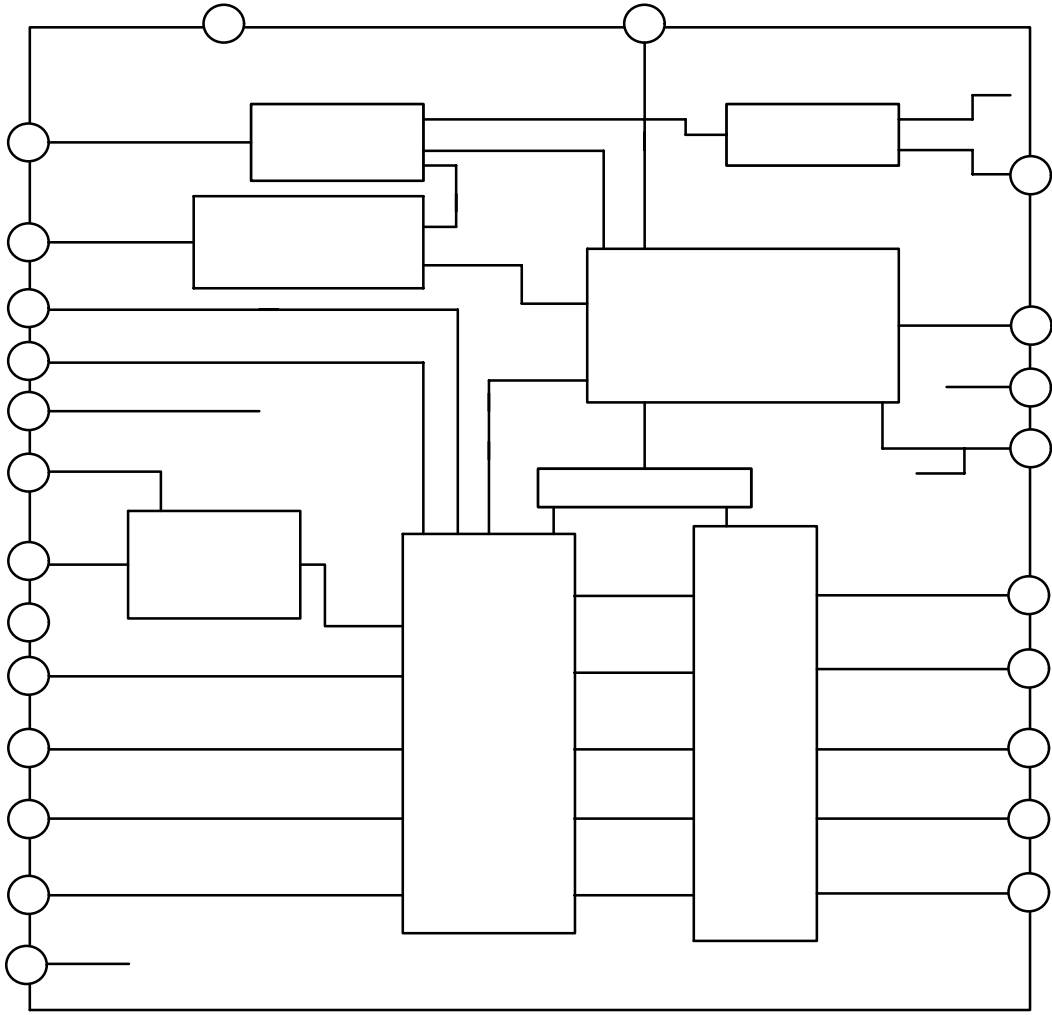


Figure 1. Typical Smart Card Interface Application

NCN8024R



# NCN8024R

## PIN FUNCTION AND DESCRIPTION

Pin #

Description

# NCN8024R

## ATTRIBUTES

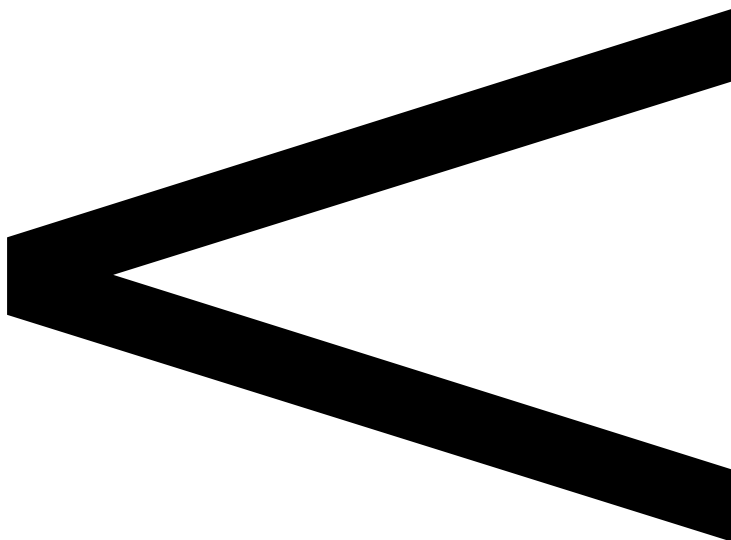
Characteristics	Values
ESD protection Human Body Model (HBM) (Note 1) Card Pins (Card Interface Pins 9 – 17) All Other Pins Machine Model (MM) Card Pins (Card Interface Pins 9 – 17) All Other Pins	8 kV 2 kV 400 V 150 V
Moisture sensitivity (Note 2) SOIC–28 and TSSOP–28	Level 3
Flammability Rating Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latch–up Test	

1. Human Body Model (HBM), R = 1500 Ω, C = 100 pF.
2. For additional information, see Application Note AND8003/D.

## MAXIMUM RATINGS (Note 3)

Rating	Symbol	Value	Unit
DC/DC Converter Power Supply Voltage	$V_{DDP}$	$-0.3 \leq V_{DDP} \leq 5.5$	V
Power Supply from Microcontroller Side	$V_{DD}$	$-0.3 \leq V_{DD} \leq 5.5$	V

EꝀ(u.58900 V)5(Tj5758 0t4 1 Tf1.3.ac.0949V)TjET525.525.203 503.66 27194.589 T659ss m-.jET525.203 501018 Tc(D27.4772 Tm-.0021 TcyD27.4772 wA



# NCN8024R

## POWER SUPPLY SECTION ( $V_{DD} = 3.3\text{ V}$ ; $V_{DDP} = 5\text{ V}$ ; $T_{amb} = 25\text{ C}$ ; $F_{CLKIN} = 10\text{ MHz}$ )

Symbol	Rating	Min	Typ	Max	Unit
$V_{DDP}$	DC/DC Converter Power Supply, CRD_V <sub>CC</sub> = 5 V $I_{CC1} \leq$				

# NCN8024R

## HOST INTERFACE SECTION CLKIN, RSTIN, I/Ouc, AUX1uc, AUX2uc, CLKDIV1, CLKDIV2, $\overline{\text{CMDVCC}}$ , 5V/3V

( $V_{DD} = 3.3\text{ V}$ ;  $V_{DDP} = 5\text{ V}$ ;  $T_{amb} = 25\text{ C}$ ;  $F_{CLKIN} = 10\text{ MHz}$ )

Symbol	Rating	Min	Typ	Max	Unit
F <sub>CLKIN</sub>	Clock Frequency on Pin CLKIN (with Divider Ratio $\geq 2$ ) (Note 6)	–	–	27	MHz
V <sub>IL</sub>	Input Voltage Level Low: CLKIN, RSTIN, I/Ouc, AUX1uc, AUX2uc, CLKDIV1, CLKDIV2, $\overline{\text{CMDVCC}}$ , 5V/3V	–0.3	–	$0.3 \times V_{DD}$	V
V <sub>IH</sub>	Input Voltage Level High: CLKIN, RSTIN, I/O, AUX1, AUX2, CLKDIV1, CLKDIV2, $\overline{\text{CMDVCC}}$ , 5V/3V	$0.7 \times V_{DD}$	–	$V_{DD} + 0.3$	V
I <sub>IL</sub>	CLKDIV1, CLKDIV2, $\overline{\text{CMDVCC}}$ , RSTIN, CLKIN, 5V/3V Low Level Input Leakage Current, V <sub>IL</sub> = 0 V	–	–	1.0	$\mu\text{A}$
I <sub>IH</sub>	CLKDIV1, CLKDIV2, $\overline{\text{CMDVCC}}$ , RSTIN, CLKIN, 5V/3V Low Level Input Leakage Current, V <sub>IH</sub> = V <sub>DD</sub>	–	–	1.0	$\mu\text{A}$
V <sub>IL</sub>	Input Voltage Level Low: I/Ouc, AUX1uc, AUX2uc	–0.3	–	0.5	V
V <sub>IH</sub>	Input Voltage Level High: I/Ouc, AUX1uc, AUX2uc	$0.7 \times V_{DD}$	–	$V_{DD} + 0.3$	V
I <sub>IL</sub>	I/Ouc, AUX1uc, AUX2uc Low Level Input Leakage Current, V <sub>IL</sub> = 0 V	–	–	600	$\mu\text{A}$
I <sub>IH</sub>	I/Ouc, AUX1uc, AUX2uc High Level Input Leakage Current, V <sub>IH</sub> = V <sub>DD</sub>	–	–	10	$\mu\text{A}$
V <sub>OH</sub>	I/Ouc, AUX1uc, AUX2uc data channels, @ Cs $\leq 30\text{ pF}$ High Level Output Voltage (CRD_I/O = CRD_AUX1 = CRD_AUX2 = CRD_V <sub>CC</sub> ) I <sub>OH</sub> = 0 I <sub>OH</sub> = –40 $\mu\text{A}$ for V <sub>DD</sub>				
V <sub>OL</sub>					
t <sub>Ri/Fi</sub>					
t <sub>Ro/Fo</sub>					

# NCN8024R

## SMART CARD INTERFACE SECTION, CRD\_IO, CRD\_AUX1, CRD\_AUX2, CRD\_CLK, CRD\_RST, CRD\_PRES, CRD\_PRES (V<sub>DD</sub> = 3.3 V; V<sub>DDP</sub> = 5 V; T<sub>amb</sub> = 25 °C; F<sub>CLKIN</sub> = 10 MHz)

Symbol	Rating	Min	Typ	Max	Unit
V <sub>OH</sub> V <sub>OL</sub>	CRD_RST @ CRD_V <sub>CC</sub> = 3.0 V, 5.0 V Output RESET V <sub>OH</sub> @ I <sub>rst</sub> = -200 μA Output RESET V <sub>OL</sub> @ I <sub>rst</sub> = 200 μA	0.9 x CRD_V <sub>CC</sub> 0	- -	CRD_V <sub>CC</sub> 0.20	V V
V <sub>OH</sub> V <sub>OL</sub>	Output RESET V <sub>OH</sub> @ I <sub>rst</sub> = -20 mA Output RESET V <sub>OL</sub> @ I <sub>rst</sub> = 20 mA	0 CRD_V <sub>CC</sub> - 0.4	- -	0.4 CRD_V <sub>CC</sub>	V V
t <sub>R</sub>	Output RESET Risettime @ C <sub>out</sub> = 100 pF (Note 7)	-	-	100	ns
t <sub>F</sub>	Output RESET Falltime @ C <sub>out</sub> = 100 pF (Note 7)	-	-	100	ns
t <sub>d</sub>	RSTIN to CRD_RST Delay – Reset Enabled (Note 7)	-	-	2	μs
F <sub>CRDCLK</sub>	CRD_CLK @ CRD_V <sub>CC</sub> = 3.0 V or 5.0 V Output Frequency (Note 7)	-	-	18	MHz
V <sub>OH</sub> V <sub>OL</sub>	Output CRD_CLK V <sub>OH</sub> @ I <sub>clk</sub> = -200 μA Output CRD_CLK V <sub>OL</sub> @ I <sub>clk</sub> = 200 μA	0.9 x CRD_V <sub>CC</sub> 0	- -	CRD_V <sub>CC</sub> +0.2	V V
V <sub>OH</sub> V <sub>OL</sub>	Output CRD_CLK V <sub>OH</sub> @ I <sub>clk</sub> = -70 mA Output CRD_CLK V <sub>OL</sub> @ I <sub>clk</sub> = 70 mA	0 CRD_V <sub>CC</sub> - 0.4	- -	0.4 CRD_V <sub>CC</sub>	V V
F <sub>DC</sub>	Output Duty Cycle (Note 7)	45	-	55	%
t <sub>rills</sub> t <sub>ulsa</sub>	Rise & Fall time (Note 5) Output CRD_CLK Risettime @ C <sub>out</sub> = 30 pF Output CRD_CLK Falltime @ C <sub>out</sub> = 30 pF	- -	- -	16 16	ns ns
SR	Slew Rate @ C <sub>out</sub> = 33 pF (Note 7)	0.2	-	-	V/ns



# NCN8024R

**SMART CARD INTERFACE SECTION, CRD\_IO, CRD\_AUX1, CRD\_AUX2, CRD\_CLK, CRD\_RST, CRD\_PRES, CRD\_PRES** ( $V_{DD} = 3.3\text{ V}$ ;  $V_{DDP} = 5\text{ V}$ ;  $T_{amb} = 25\text{ C}$ ;  $F_{CLKIN} = 10\text{ MHz}$ )

Symbol	Rating	Min	Typ	Max	Unit
$I_{IH}$	CRD_PRES, $\overline{\text{CRD\_PRES}}$ High level input leakage current, $V_{IH} = V_{DD}$		3		
$I_{IL}$	CRD_PRES, $\overline{\text{CRD\_PRES}}$ Low level input leakage current, $V_{IL} = 0\text{ V}$		3		

bridge with  $R1 = 56\text{ k}\Omega$ ,  $R2 = 42\text{ k}\Omega$  and  $V_{\text{POR}} = 1.20\text{ V}$  typical the  $V_{\text{DD}}$  dropout detection level can be increased up to:

$$\text{UVLO} = \frac{59\text{k} + 42\text{k}}{42\text{k}} V_{\text{POR}} = 2.75\text{ V}$$

The minimum dropout detection voltage should be higher than 2 V.

The maximum detection level may be up to  $V_{\text{DD}}$ .

**CLOCK DIVIDER:**

The input clock can be divided by 1/1, 1/2, 1/4, or 1/8, depending upon the specific application, prior to be applied to the smart card driver. These division ratios are programmed using pins CLKDIV1 and CLKDIV2 (see Table 1). The input clock is provided externally to pin CLKIN.

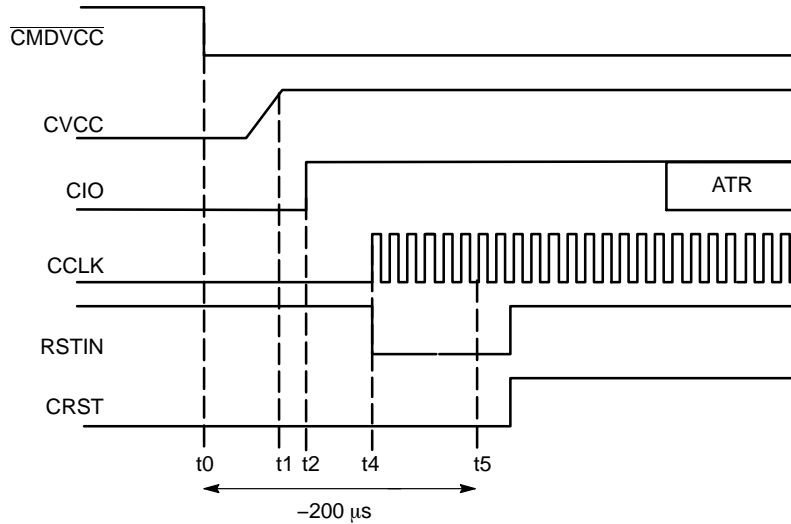
**Table 1. Clock Frequency Programming**

CLKDIV1	CLKDIV2	F <sub>CRD_CLK</sub>
0		

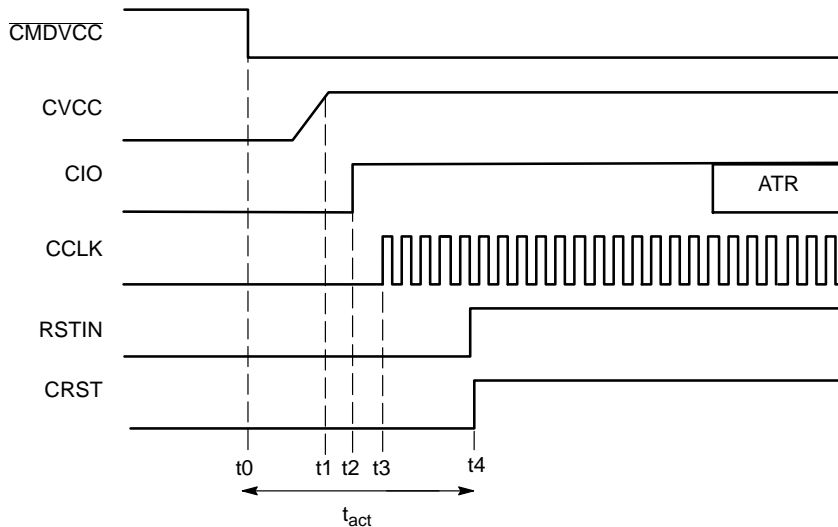
## NCN8024R

If controlling the clock with RSTIN is not necessary (**Normal Mode**), then /CMDVCC can be set LOW with RSTIN LOW. In that case, CLK will start minimum 500 ns after the transition on I/O (Figure 5), and to obtain an ATR, CRST can be set High by RSTIN also about 500 ns after the clock channel activation (tact).

The internal activation sequence activates the different channels according to a specific hardware built it sequencing internally defined but at the end the actual activation sequencing is the responsibility of the application software and can be redefined by the micro controller to comply with the different standards and the different ways the standards manage this activation (for example light differences exist between the EMV and the ISO7816 standards).



**Figure 4. Activation Sequence – RSTIN mode (RSTIN Starting High)**



**Figure 5. Activation Sequence – Normal Mode**

### POWER-DOWN

When the communication session is completed the NCN8024R runs a deactivation sequence by setting High CMDVCC. The below power down sequence is executed:

CRD\_RST is forced to Low

CRD\_CLK is set Low 12 μs after CRD\_RST.

CRD\_IO, CRD\_AUX1 and CRD\_AUX2 are pulled Low

Finally CRD\_VCC supply can be shut off.

## NCN8024R

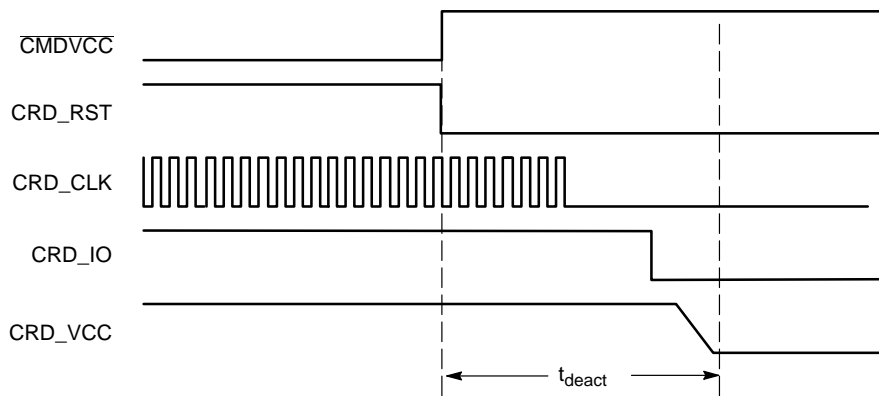


Figure 6. Deactivation Sequence

### FAULT DETECTION

In order to protect both the interface and the external smart card, the NCN8024R provides security features to prevent failures or damages as depicted here after.

Card extraction detection

$V_{DD}$  under voltage detection

Short circuit or overload on  $CRD\_VCC$

Card pin current limitation: in the case of a short circuit to ground. No feedback is provided to the external MPU.

LDO operation: the internal circuit continuously senses the  $CRD\_VCC$  voltage (in the case of either over or under voltage situation).

LDO operation: under voltage detection on  $V_{DDP}$  or overload on  $VUP$

Overheating

Card pin current limitation: in the case of a short circuit to ground. No feedback is provided to the external MPU

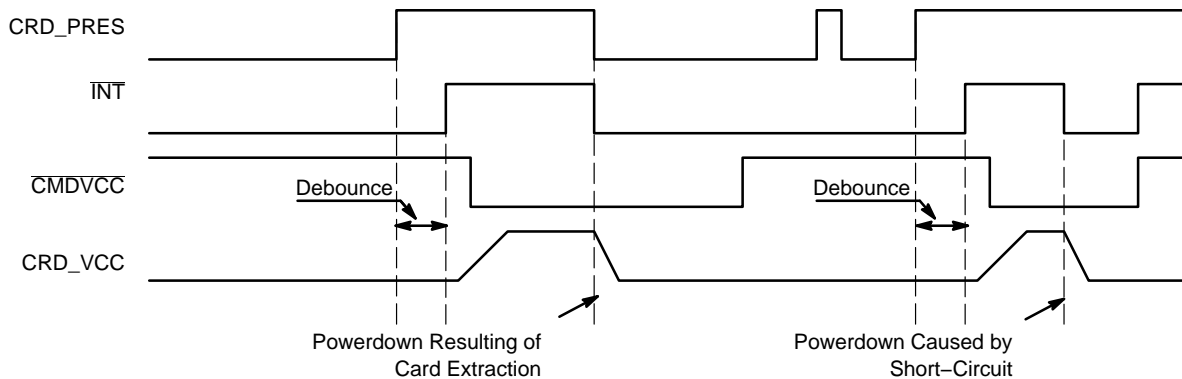


Figure 7. Fault Detection and Interrupt Management

### Interrupt Pin Management:

A card session is opened by toggling  $\overline{CMDVCC}$  High to Low.

Before a card session,  $\overline{CMDVCC}$  is supposed to be in a High position.  $\overline{INT}$  is Low if no card is present in the card connector (Normally open or normally closed type).  $\overline{INT}$  is High if a card is present. If a card is inserted ( $\overline{INT} = \text{High}$ ) and if  $V_{DD}$  drops below the UVLO threshold then  $\overline{INT}$  pin drops Low immediately. It turns back High when  $V_{DD}$  increases again over the UVLO limit (including hysteresis), a card being still present.

During a card session,  $\overline{CMDVCC}$  is Low and  $\overline{INT}$  pin goes Low when a fault is detected. In that case a deactivation is immediately and automatically performed (see Figure 6). When the microcontroller resets  $\overline{CMDVCC}$  to High it can sense the  $\overline{INT}$  level again after having got completed the deactivation.

As illustrated by Figure 7 the device has a debounce timer of 8 ms typical duration. When a card is inserted, output  $\overline{INT}$  goes High only at the end of the debounce time. When the card is removed a deactivation sequence is automatically and immediately performed and  $\overline{INT}$  goes Low.

# NCN8024R

## ESD PROTECTION

The NCN8024R includes devices to protect the pins against the ESD spikes voltages. To cope with the different ESD voltages developed across these pins, the built in structures have been designed to handle either 2 kV, when related to the micro controller side, or 8 kV when connected with the external contacts (HBM model). Practically, the

CRD\_RST, CRD\_CLK, CRD\_IO, CRD\_AUX1, CRD\_AUX2, CRD\_PRES and  $\overline{\text{CRD\_PRES}}$  pins can sustain 8 kV. The CRD\_VCC pin has the same ESD protection and can source up to 70 mA continuously, the absolute maximum current being internally limited with a max at 150 mA. The CRD\_VCC current limit depends on  $V_{\text{DDP}}$  and CRD\_VCC.

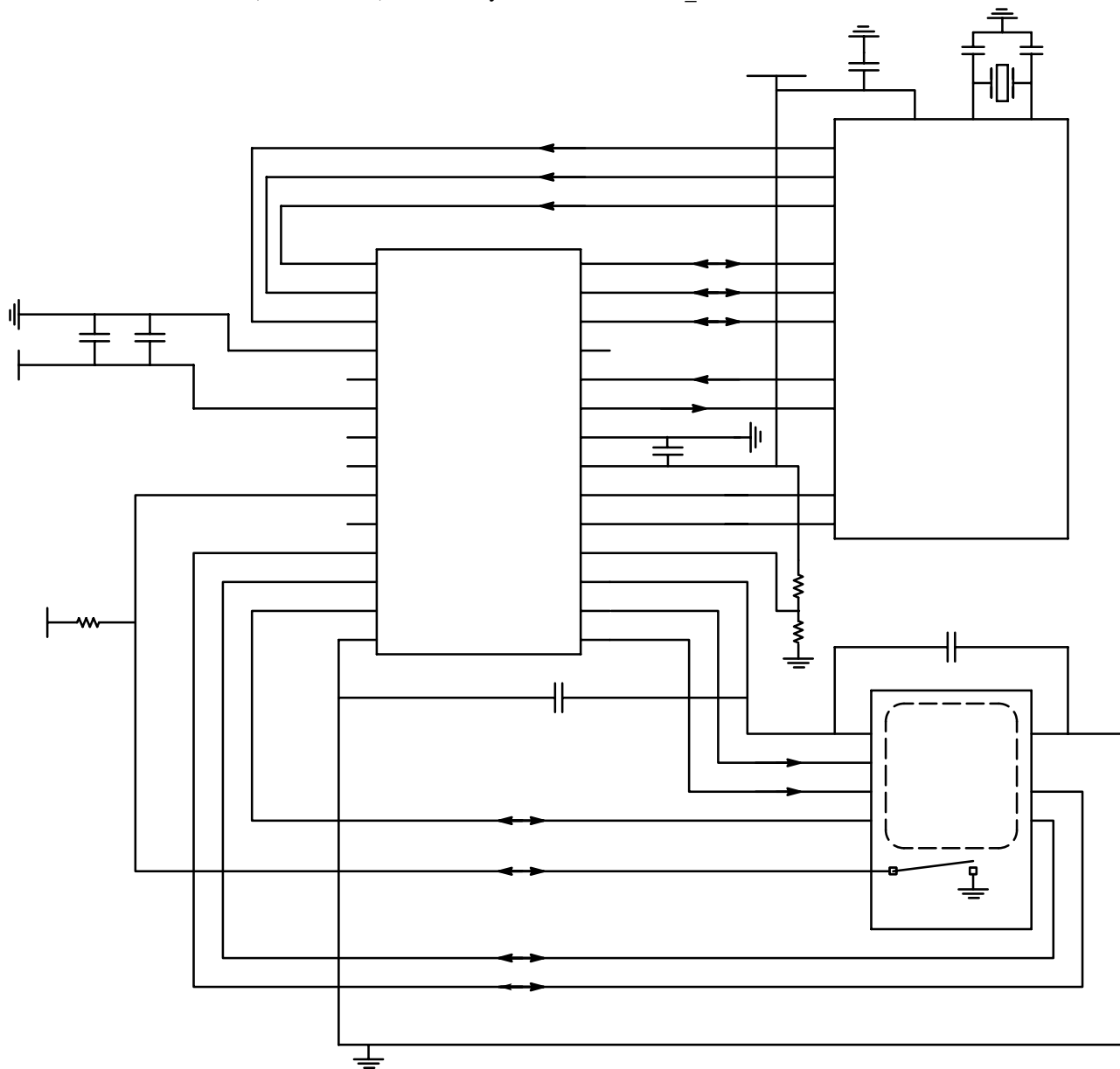
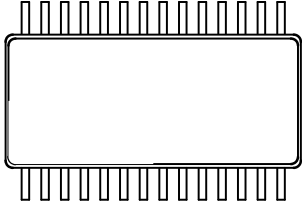


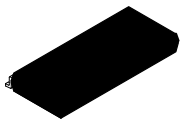
Figure 8. Application Schematic

# NCN8024R

## PACKAGE DIMENSIONS

TSSOP28  
CASE 948AA  
ISSUE A

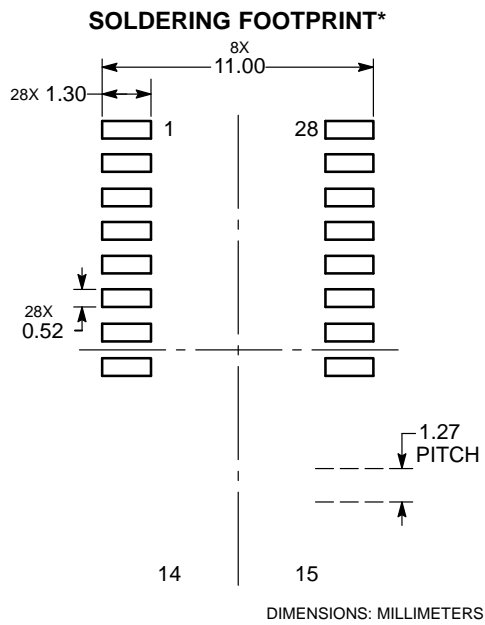




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SOIC-28 WB  
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